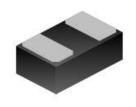


PESDNC2FD3V3BS

Bi-directional 3.3V Normal Capacitance ESD Protector

Description

The PESDNC2FD3V3BS protects sensitive semiconductor components from damage or upset due to electrostatic discharge (ESD) and other voltage induced transient events. They feature large cross-sectional area junctions for conducting high transient currents, offer desirable electrical characteristics for board level protection, such as fast response time, low operating voltage. It gives designer the flexibility to protect one bi-directional line in applications where arrays are not practical.



DFN1006-2L(Bottom View)

Feature

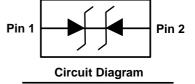
- DFN1006-2L package
- Replacement for MLV(0402)
- Bidirectional configurations
- Response time is typically < 1ns</p>
- Low clamping voltage
- RoHS compliant
- Transient protection for data lines to IEC61000-4-2(ESD)
 ±25kV(air), ±25kV(contact); IEC61000-4-4 (EFT) 40A (5/50ns)

Applications

- Cellular phones
- Portable devices
- Digital cameras
- Power supplies

Mechanical Characteristics

- Mounting position: Any
- Qualified max reflow temperature:260°C
- Device meets MSL 1 requirements
- DFN1006-2L without plating



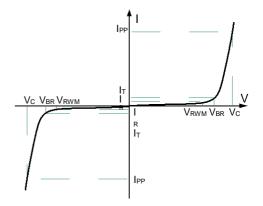


Marking (Top View)

PESDNC2FD3V3BS

Electronics Parameter

Symbol	Parameter		
Vrwm	Peak Reverse Working Voltage		
IR	Reverse Leakage Current @ V _{RWM}		
VBR	Breakdown Voltage @ I⊤		
IT	Test Current		
IPP	Maximum Reverse Peak Pulse Current		
Vc	Clamping Voltage @ IPP		
P _{PP}	Peak Pulse Power		
CJ	Junction Capacitance		
IF	Forward Current		
VF	Forward Voltage @ IF		



Electrical characteristics per line@25°C (unless otherwise specified)

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Units
Reverse Stand-off Voltage	Vrwm				3.3	V
Reverse Breakdown Voltage	V _{BR}	It = 1mA 4.5			6.5	V
Reverse Leakage Current	I _R	V _{RWM} = 3.3V T=25°C			1.0	μA
Clamping Voltage	Vcl	IPP=16A tp=100ns		10		V
Clamping Voltage	Vc	I _{PP} =5A t _P = 8/20µs			10.5	V
Junction Capacitance	Cj	V _R =0V f = 1MHz		9.5		pF

Absolute maximum rating@25°C

Rating	Symbol	Value	Units
Unidirectional Peak Pulse Power	P _{pp}	60	W
Operating Temperature	TJ	-55 to 150	°C
Storage Temperature	Тѕтс	-55 to 150	°C

PESDNC2FD3V3BS

Typical Characteristics

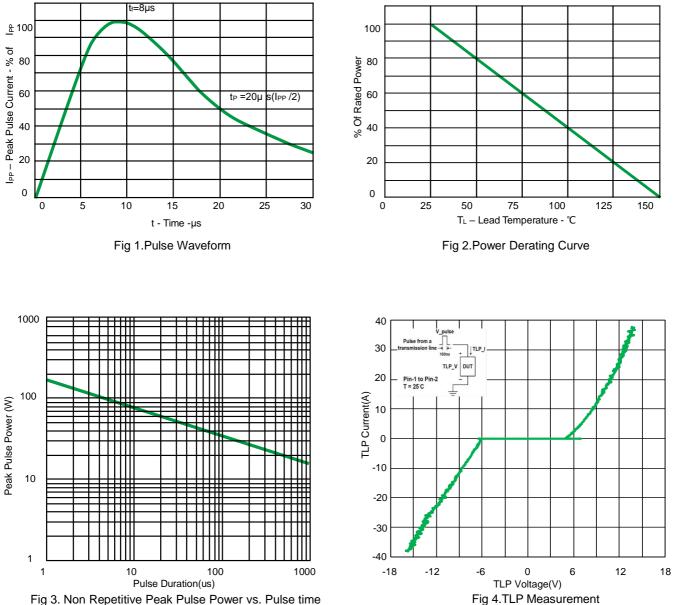
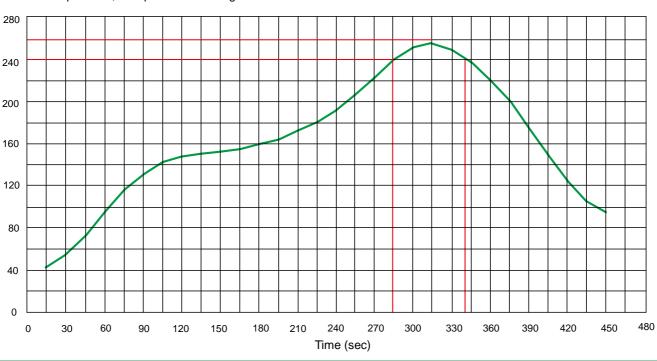


Fig 3. Non Repetitive Peak Pulse Power vs. Pulse time

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PESDNC2FD3V3BS

Solder Reflow Recommendation



Peak Temp=257°C, Ramp Rate=0.802deg. °C/sec

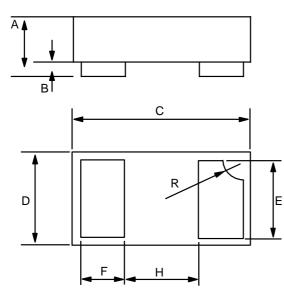
PCB Design

For TVS diodes a low-ohmic and low-inductive path to chassis earth is absolutely mandatory in order to achieve good ESD protection. Novices in the area of ESD protection should take following suggestions to heart:

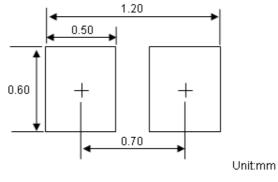
- > Do not use stubs, but place the cathode of the TVS diode directly on the signal trace.
- > Do not make false economies and save copper for the ground connection.
- > Place via holes to ground as close as possible to the anode of the TVS diode.
- > Use as many via holes as possible for the ground connection.
- > Keep the length of via holes in mind! The longer the more inductance they will have.

PESDNC2FD3V3BS

Product dimension (DFN1006-2L)



Dim	Incl	hes	Millimeters		
	MIN	МАХ	MIN	МАХ	
A	0.013	0.020	0.34	0.498	
В	0.000	0.002	0.00	0.05	
С	0.037	0.043	0.95	1.080	
D	0.022	0.027	0.55	0.680	
E	0.016	0.024	0.40	0.60	
F	0.008	0.012	0.20	0.30	
н	0.015Typ.		0.40Тур.		
R	0.001	0.005	0.05	0.15	



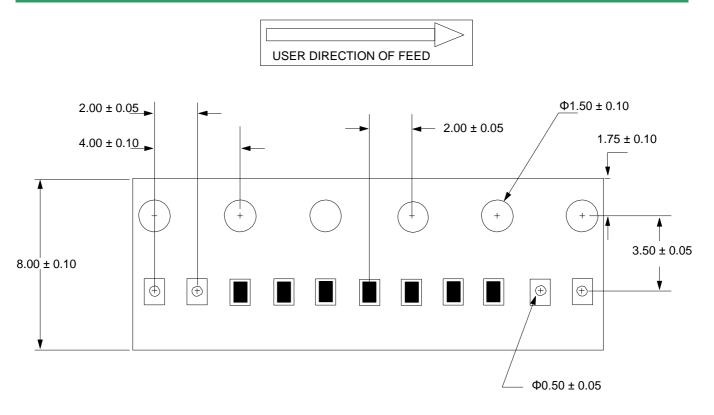
Suggested PCB Layout

Ordering information

Device	Package	Reel	Shipping	
PESDNC2FD3V3BS	DFN1006-2L (Pb-Free)	13"	40000 / Tape & Reel	

PESDNC2FD3V3BS

Load with information





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